BGU7032

1 GHz wideband low-noise amplifier with bypass Rev. 2 — 14 September 2010 Pro

Product data sheet

1. **Product profile**

1.1 General description

The BGU7032 MMIC is a wideband amplifier with bypass mode. It is designed specifically for high linearity, low-noise applications over a frequency range of 40 MHz to 1 GHz. It is especially suited to Set-Top Box applications.

The LNA is housed in a 6-pin SOT363 plastic SMD package.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Internally biased
- Programmable between G_p = 10 dB and bypass
- Flat gain between 40 MHz and 1 GHz
- Noise figure of 4.5 dB
- High linearity with an IP3_O of 29 dBm
- 75 Ω input and output impedance
- Power-down during bypass mode
- Bypass mode current consumption < 5 mA
- ESD protection > 2 kV Human Body Model (HBM) on all pins

1.3 Applications

- Terrestrial and cable Set-Top Boxes (STB)
- Silicon and "Can" tuners
- Personal and Digital Video Recorders (PVR and DVR)
- Home networking and in-house signal distribution



1 GHz wideband low-noise amplifier with bypass

1.4 Quick reference data

Table 1. Quick reference data

 T_{amb} = 25 °C; typical values at V_{CC} = 5 V; Z_{S} = Z_{L} = 75 Ω ; R_{bias} = 43 Ω ; 40 MHz \leq f_{1} \leq 1000 MHz.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CC}	supply voltage	RF input AC coupled		4.75	5.0	5.25	V
I _{CC(tot)}	total supply current	G _p = 10 dB mode	[1]	-	43	-	mΑ
		bypass mode	[1]	-	4	-	mΑ
T _{amb}	ambient temperature			-10	-	+70	°C
NF	noise figure	G _p = 10 dB mode	<u>[1]</u>	-	4.5	-	dB
		bypass mode	<u>[1]</u>	-	2.5	-	dB
P _{L(1dB)}	output power at 1 dB gain compression	1 GHz; $G_p = 10 \text{ dB}$ mode	<u>[1]</u>	-	14	-	dBm
IP3 _O	output third-order intercept point	G _p = 10 dB mode	[1][2]	-	29	-	dBm

^[1] Mode depends on setting of V_{CTRL} ; see <u>Table 8</u>.

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	RF_OUT		
2	V_{CC}	6 5 4	3 2
3	n.c.		6—
4	CTRL	0	
5	GND	□1 □2 □3	5 4 sym141
6	RF_IN		5,

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BGU7032	-	plastic surface-mounted package; 6 leads	SOT363		

4. Marking

Table 4. Marking codes

Type number	Marking code
BGU7032	SD%

Note: % character indicates the location of production.

BGU7032

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^[2] The fundamental frequency (f_1) is 1000 MHz. The intermodulation product (IM3) is $2 \times f_2 - f_1$, where $f_2 = f_1 \pm 1$ MHz. Input power $P_i = -10$ dBm.

1 GHz wideband low-noise amplifier with bypass

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage	RF input AC coupled		-0.6	5.25	V
$V_{\text{ctrl}(Gp)}$	power gain control voltage	pin CTRL	[1]	0	V_{CC}	V
I _{CC(tot)}	total supply current			-	60	mA
P _{tot}	total power dissipation	T _{sp} ≤ 100 °C	[2]	-	250	mW
Pi	input power	single tone		-	10	dBm
T _{stg}	storage temperature			-65	+150	°C
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-10	+70	°C
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM); according to JEDEC standard 22-A114E		2	-	kV

^[1] $V_{ctrl(Gp)}$ must not exceed V_{CC} ; I_{CTRL} must be limited to 5 mA (maximum).

Remark: $V_{ctrl(Gp)}$ must not exceed V_{CC} ; I_{CTRL} must be limited to a maximum of 5 mA.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		240	K/W

7. Characteristics

Table 7. Characteristics

 T_{amb} = 25 °C; typical values at V_{CC} = 5 V; Z_{S} = Z_{L} = 75 Ω ; R_{bias} = 43 Ω ; 40 MHz \leq f_{1} \leq 1000 MHz.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CC}	supply voltage	RF input AC coupled		4.75	5.0	5.25	V
I _{CC(tot)}	total supply current	G _p = 10 dB mode	[1]	-	43	-	mΑ
		bypass mode	[1]	-	4	-	mΑ
$ s_{21} ^2$	insertion power gain	G _p = 10 dB mode	[1]	-	10	-	dB
		bypass mode	[1]	-	-2	-	dB
SL _{sl}	slope straight line			-	-1	-	dB
FL	flatness of frequency response			-	-0.2	-	dB
NF	noise figure	G _p = 10 dB mode	[1]	-	4.5	-	dB
		bypass mode	[1]	-	2.5	-	dB
RL_{in}	input return loss	G _p = 10 dB mode	[1]	-	18	-	dB
		bypass mode	[1]	-	8	-	dB

BGU703

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^[2] T_{sp} is the temperature at the solder point of the ground lead.

1 GHz wideband low-noise amplifier with bypass

Table 7. Characteristics ... continued

 T_{amb} = 25 °C; typical values at V_{CC} = 5 V; Z_{S} = Z_{L} = 75 Ω ; R_{bias} = 43 Ω ; 40 MHz \leq f_{1} \leq 1000 MHz.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
RLout	output return loss	$G_p = 10 \text{ dB mode}$	<u>[1]</u>	-	12	-	dB
		bypass mode	[1]	-	8	-	dB
P _{L(1dB)}	output power at 1 dB gain compression	1 GHz; $G_p = 10 \text{ dB}$ mode	[1]	-	14	-	dBm
IP3 _O	output third-order intercept point	G _p = 10 dB mode	[1][2]	-	29	-	dBm
		bypass mode	[1][2]	-	29	-	dBm

^[1] Mode depends on setting of $V_{ctrl(Gp)}$ (V_{CTRL}); see <u>Table 8</u>.

Table 8. Gain selection (pin CTRL)

-10 °C ≤ T_{amb} ≤ +70 °C; recommended power-up condition: V_{CTRL} = logic 0 or < 0.7 V.

V _{ctrl(Gp)} (V _{CTRL}) (V)	Mode
≤ 0.7	bypass
≥ 4.3	G _p = 10 dB

Remark: V_{ctrl(Gp)} must not exceed V_{CC}; I_{CTRL} must be limited to a maximum of 5 mA.

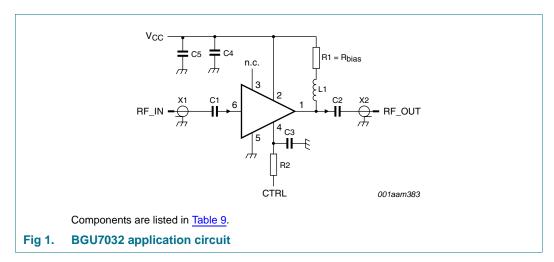
^[2] The fundamental frequency (f_1) is 1000 MHz. The intermodulation product (IM3) is $2 \times f_2 - f_1$, where $f_2 = f_1 \pm 1$ MHz. Input power $P_i = -10$ dBm.

1 GHz wideband low-noise amplifier with bypass

8. Application information

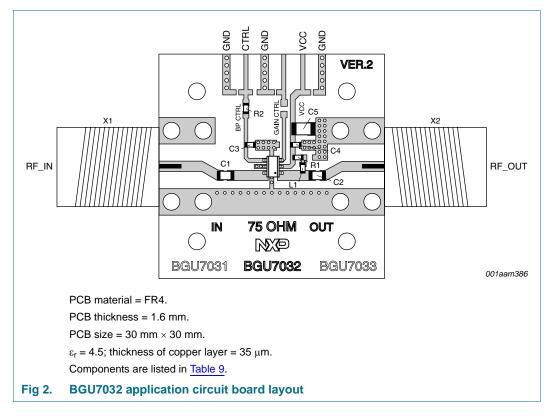
Other applications are possible. Please contact your local sales representative for more information. Application notes are available on the NXP website.

8.1 Application circuit



All control and supply lines must be decoupled properly. The decoupling capacitors must be placed as close to the device as possible.

8.2 Application circuit board layout



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Table 9.List of componentsSee Figure 1 and Figure 2.

Component	Description	Value	Re	marks	Function
C1, C2	capacitor	10 nF			DC blocking
C3, C4	capacitor	10 nF			decoupling
C5	capacitor	10 μF			decoupling
L1	chip ferrite bead	$1.5~\mathrm{k}\Omega$	[1] Mu	rata BLM18HE152SN1DF	RF choke
R1	resistor	43 Ω	[1] R _{bi}	as	bias setting
R2	resistor	$1.8~\mathrm{k}\Omega$			current limiting
X1, X2	connector	75 Ω		connector, edge mount PCB ow type, Bomar 861V509ER	input/output G

^[1] L1 and R1 must have a power rating of 0.1 W or higher.

1 GHz wideband low-noise amplifier with bypass

9. Package outline

Plastic surface-mounted package; 6 leads **SOT363** Α Χ = v M A ⊕ w M B е detail X **DIMENSIONS (mm are the original dimensions)** Α₁ UNIT Α D Ε С Q HΕ Lp у max 0.25 0.10 0.45 0.15 2.2 1.8 2.2 2.0 0.30 1.35 0.25 1.1 0.65 8.0 0.20 1.15 0.15

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION		
SOT363			SC-88	$ \ \ \bigoplus \bigoplus$	04-11-08 06-03-16	

Fig 3. Package outline SOT363

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1 GHz wideband low-noise amplifier with bypass

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
AC	Alternating Current
DC	Direct Current
LNA	Low-Noise Amplifier
MMIC	Monolithic Microwave Integrated Circuit
PCB	Printed-Circuit Board
RF	Radio Frequency
SMD	Surface-Mounted Device

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGU7032 v.2	20100914	Product data sheet	-	BGU7032 v.1
Modifications:	 The status 	of this data sheet has been	changed to Product dat	a sheet.
BGU7032 v.1	20100817	Preliminary data sheet	-	-

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12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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1 GHz wideband low-noise amplifier with bypass

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1 GHz wideband low-noise amplifier with bypass

14. Contents

1	Product profile	. 1
1.1	General description	. 1
1.2	Features and benefits	. 1
1.3	Applications	. 1
1.4	Quick reference data	. 2
2	Pinning information	. 2
3	Ordering information	. 2
4	Marking	. 2
5	Limiting values	. 3
6	Thermal characteristics	
7	Characteristics	. 3
8	Application information	. 5
8.1	Application circuit	. 5
8.2	Application circuit board layout	. 5
9	Package outline	. 7
10	Abbreviations	. 8
11	Revision history	. 8
12	Legal information	. 9
12.1	Data sheet status	. 9
12.2	Definitions	. 9
12.3	Disclaimers	. 9
12.4	Trademarks	10
13	Contact information	10
14	Contents	11

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